

09/18/01

ISSUE CLASSIFICATION	
Class	Subclass

N

PATENT NUMBER

U.S. **UTILITY** Patent Application

**O.I.P.E.**

PATENT DATE

**SCANNED**

9.4

APPLICATION NO. 09/955641	CONT/PRIOR	CLASS 365	SUBCLASS 104	ART UNIT 2818 2824	EXAMINER HIEN NGUYEN
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## APPLICANTS

Jack Payne

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**FILE**

Semiconductor memory cell and memory array using a breakdown phenomena in an ultra-thin dielectric

PTO-2040  
12/89

## ISSUING CLASSIFICATION

[illegible]

<input type="checkbox"/> <b>TERMINAL DISCLAIMER</b>	<b>DRAWINGS</b>			<b>CLAIMS ALLOWED</b>	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
<input type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	_____ (Assistant Examiner)           _____ (Date)			<b>NOTICE OF ALLOWANCE MAILED</b>	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent. No. _____ _____ _____	_____          _____ (Primary Examiner)           _____ (Date)			<b>ISSUE FEE</b>	
				Amount Due           Date Paid	
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